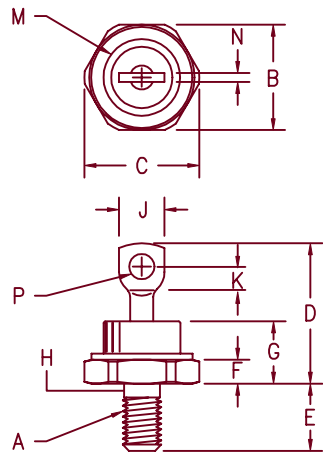


# Silicon Power Rectifier S/R38 Series



- Notes:
- 1/4-28 UNF-3A
  - Full threads within 2 1/2 threads
  - For Reverse Polarity add R to Part Number  
Standard Polarity: Stud is Cathode  
Reverse polarity: Stud is Anode

Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	---	---	---	---	1
B	.667	.687	16.95	17.44	
C	---	.793	---	20.14	
D	---	1.00	---	25.40	
E	.422	.453	10.72	11.50	
F	.115	.200	2.93	5.08	
G	---	.450	---	11.43	
H	.220	.249	5.59	6.32	2
J	.250	.375	6.35	9.52	
K	.156	---	3.97	---	
M	---	.667	---	16.94	Dia
N	---	.080	---	2.03	
P	.140	.175	3.56	4.44	Dia

D0203AB (D05)

Microsemi Catalog Number		Peak Reverse Voltage
Standard	Reverse	
S3820	R3820	200V
S3840	R3840	400V
S3860	R3860	600V
S3880	R3880	800V
S38100	R38100	1000V
S38120	R38120	1200V

- Glass to metal construction
- Highest current DO-5 available
- Glass passivated die
- 1800 amps surge rating
- VRRM to 1200V

## Electrical Characteristics

Average forward current	IF(AV) 100 Amps	TC = 144°C, half sine wave, RθJC = 0.5°C/W 8.3ms, half sine, TJ = 200°C
Maximum surge current	IFSM 1800 Amps	
Max I <sup>2</sup> t for fusing	I <sup>2</sup> t 13440 A <sup>2</sup> s	
Max peak forward voltage	VFM 1.15 Volts	IFM = 200A; TJ = 25°C*
Max peak reverse current	IRM 25 μA	VRRM, TJ = 25°C
Max peak reverse current	IRM 3.0 mA	VRRM, TJ = 150°C
Max Recommended Operating Frequency	10kHz	

\*Pulse test: Pulse width 300 μsec. Duty cycle 2%

## Thermal and Mechanical Characteristics

Storage temperature range	TSTG	-65°C to 200°C
Operating junction temp range	TJ	-65°C to 200°C
Maximum thermal resistance	RθJC	0.5°C/W Junction to Case
Mounting torque		25-30 inch pounds
Weight		.6 ounces (17 grams) typical

12-14-00 Rev. 1

# S/R38

Figure 1  
Typical Forward Characteristics

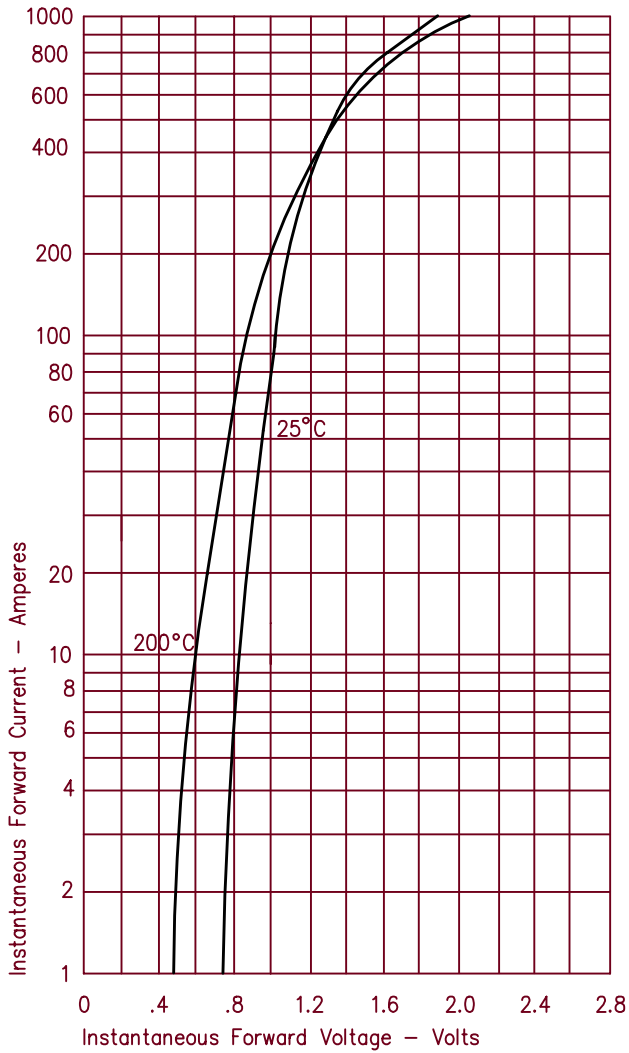


Figure 3  
Forward Current Derating

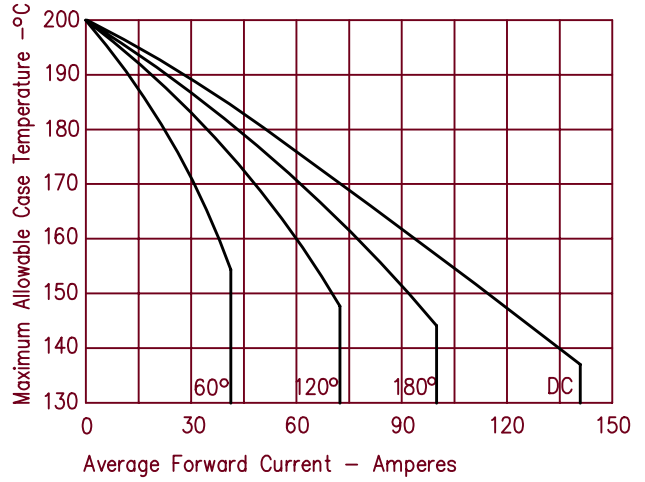


Figure 4  
Maximum Forward Power Dissipation

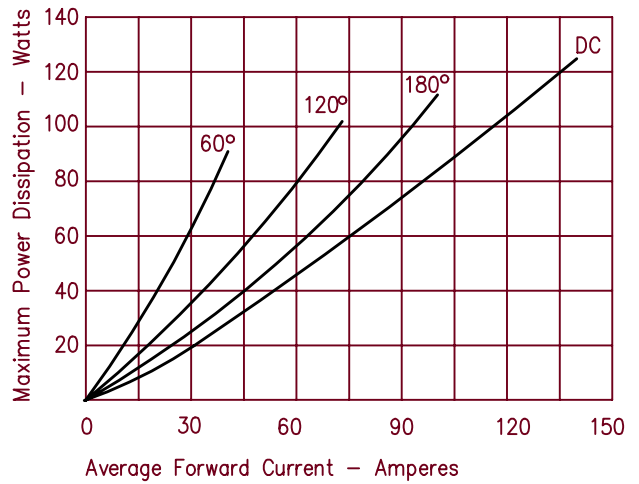


Figure 2  
Typical Reverse Characteristics

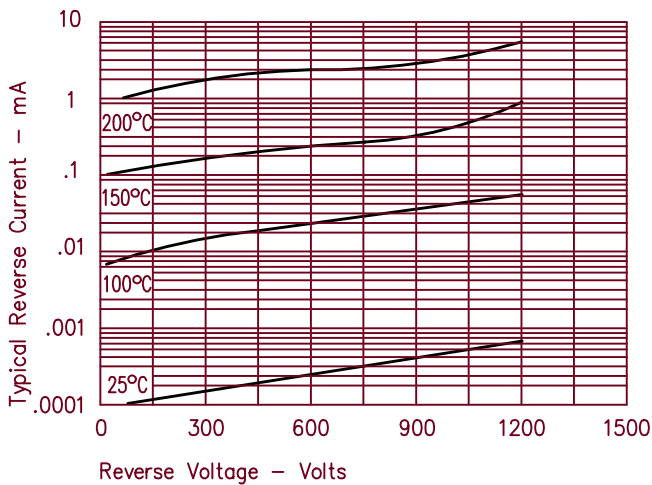


Figure 5  
Transient Thermal Impedance

